TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WT74FU

### D-Type Flip-Flop with Preset and Clear

The TC7WT74FU is high speed CMOS D-TYPE FLIP-FLOP fabricated with silicon gate CMOS technology.

It achieves the high speed operation similar to equivalent Bipolar schottky TTL while maintaining the CMOS low power dissipation.

The input threshold levels are compatible with  $\ensuremath{\mathsf{TTL}}$  output voltage.

The signal level applied to the D-INPUT is tranceferred to

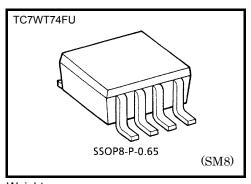
Q-OUTPUT during the positive going trasition of the CK pulse.

CLEAR and PRESET are independent of the CK and are accompished by setting the appropriate input low.

All inputs are equipped with protection circuits against static dichage or transient excess voltage.

#### **Features**

- High speed: f<sub>MAX</sub> = 53 MHz(typ.) at V<sub>CC</sub> = 5 V
- Low power dissipation: I<sub>CC</sub> = 2 μA (max) at Ta = 25°C
- Compatible with TTL inputs: V<sub>IL</sub> = 0.8 V(max) at Ta=25°C
- · Output drive capability: 10 LSTTL Loads
- Symmetrical output impedance: |I<sub>OH</sub>| = I<sub>OL</sub> = 4 mA (min)



Weight SSOP8-P-0.65: 0.02 g (typ.)

### Absolute Maximum Ratings (Ta = 25°C)

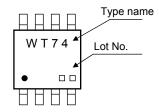
Characteristics	Symbol	Rating	Unit
Supply voltage range	V <sub>CC</sub>	−0.5 to 7	V
DC input voltage	V <sub>IN</sub>	–0.5 to V <sub>CC</sub> + 0.5	V
DC output voltage	V <sub>OUT</sub>	–0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> /ground current	Icc	±25	mA
Power dissipation	PD	300	mW
Storage temperature	T <sub>stg</sub>	-65 to 150	°C
Lead temperature (10s)	TL	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating

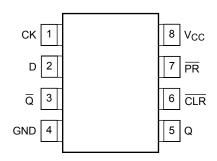
temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

### Marking



#### Pin Assignment (top view)

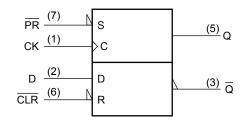


### **Truth Table**

	Inp	uts		Outputs		Function		
CLR	PR	D	CK	Q	Q			
L	Н	Х	Х	L	Н	Clear		
Н	L	Х	Х	Н	L	Preset		
L	L	Х	Х	Н	Н	_		
Н	Н	L		L	Н	_		
Н	Н	Н	<u></u>	Н	L	_		
Н	Н	Х	¬_	Qn	Qn	No Change		

### X: Don't care

# **Logic Diagram**



# **Operating Ranges**

Characteristics	Symbol	Rating	Unit
Supply voltage	V <sub>CC</sub>	4.5 to 5.5	٧
Input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V
Output voltage	V <sub>OUT</sub>	0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500	ns

### **DC Electrical Characteristics**

Charac	Characteristics Symbol Test Condition				Га = 25°C	)	Ta = -4	0 to 85°C	Unit						
Charac			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic						
Input	High level	V <sub>IH</sub>		_	4.5 to 5.5	2.0	_	_	2.0		V				
voltage	Low level	V <sub>IL</sub>		_	4.5 to 5.5	_	_	0.8	_	0.8	V				
		High level V <sub>OH</sub> V <sub>IN</sub> = V <sub>IL</sub> of	VIN =	I <sub>OH</sub> = -20 μA	4.5	4.4	4.5	_	4.4	_	V				
Output High lev	High level		V <sub>IL</sub> or V <sub>IH</sub>	I <sub>OH</sub> = -4 mA	4.5	4.18	4.31	_	4.13	_					
voltage		el V <sub>OL</sub> V	V <sub>OL</sub> V	V <sub>OL</sub>	V <sub>OL</sub>	V <sub>OL</sub>	V <sub>IN</sub> =	I <sub>OL</sub> = 20 μA	4.5	_	0.0	0.10	_	0.10	V
							VOL	V <sub>IL</sub> or V <sub>IH</sub>	I <sub>OL</sub> = 4 mA	4.5	_	0.17	0.26	_	0.33
Input leakage	current	I <sub>IN</sub>	$V_{IN} = V_{CC}$	or GND	5.5	_	_	±0.1	_	±1	μА				
		Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	_	2.0	_	20.0	μА				
Quiescent supply current		I <sub>CCT</sub>		T: V <sub>IN</sub> = 0.5 V or 2.4V PUT: V <sub>CC</sub> or GND	5.5	_	_	2.0	_	2.9	mA				

# Timing Requirements (Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol Test Condition			Ta = 25°C		Ta = -40 to 85°C	Unit
Characteristics			V <sub>CC</sub> (V)	Тур	LIMIT	LIMIT	Offic
Minimum pulse width	t <sub>W</sub> (L)		4.5	_	25	29	ns
(CLOCK)	t <sub>W</sub> (H)	_	5.5		20	23	115
Minimum pulse width (CLR, PR)	t(L)		4.5	_	30	34	ns
	t <sub>W</sub> (L)	_	5.5	_	25	28	115
Minimum set-up time	ts		4.5	_	25	29	ns
			5.5	_	20	23	115
Minimum hold time	<b>4</b> .		4.5	_	10	10	ns
Minimum noid time	чh	t <sub>h</sub> —	5.5	_	8	8	115
Minimum removal time	t <sub>rem</sub> —		4.5	_	10	10	20
(CLR, PR)		5.5	_	10	10	ns	
Clock frequency	,		4.5	_	22	16	MUZ
		f —			25	19	MHz

# AC Electrical Characteristics ( $C_L = 15pF$ , $V_{CC} = 5V$ , $Ta = 25^{\circ}C$ )

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t <sub>TLH</sub> t <sub>THL</sub>	_	_	6	12	ns
Propagation delay time (CLOCK – Q, Q)	t <sub>PLH</sub>	_	_	17	28	ns
Propagation delay time (CLR, PR - Q, Q)	t <sub>PLH</sub>	_	_	20	30	ns
Maximum clock frequency	f <sub>MAX</sub>	_	24	53	_	MHz

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# AC Electrical Characteristics ( $C_L = 50pF$ , Input $t_r = t_f = 6 ns$ )

Characteristics	Symbol Test Condition			Ta = 25°C			Ta = -40	Linit	
	Symbol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
Output transition time	tTLH		4.5	_	8	15	_	19	ns
Output transition time	t <sub>THL</sub>	_	5.5	_	7	13	_	16	115
Propagation delay time	t <sub>PLH</sub>	_	4.5	_	21	33	_	41	ns
$(CLOCK - Q, \overline{Q})$	t <sub>PHL</sub>		5.5	_	19	30	_	37	
Propagation delay time	t <sub>PLH</sub>	_	4.5	_	23	35	_	43	ns
$(\overline{CLR}, \overline{PR} - Q, \overline{Q})$	t <sub>PHL</sub>		5.5	_	20	32	_	40	
Maximum alask fraguenay	£	_	4.5	22	48	_	16	_	MHz
Maximum clock frequency	f <sub>MAX</sub>			5.5	25	53	_	19	_
Input capacitance	C <sub>IN</sub>	_		_	5	10	_	10	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note)		_	34	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

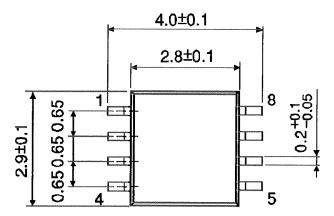
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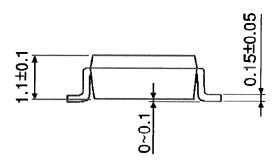
Average operating current can be obtained by the equation:

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

### **Package Dimensions**

SSOP8-P-0.65 Unit: mm





Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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